

JPW



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:
Shui-Ming Cheng, et al.

Serial No.: 10/722,218

Filed: November 25, 2003

For: SEMICONDUCTOR DEVICE
HAVING HIGH DRIVE CURRENT
AND METHOD OF MANUFACTURE
THEREFOR

§ Attorney Docket No. 2003-0959/24061.149
§
§ Customer No. 42717
§
§ Group Art Unit: 2814
§
§ Examiner: Wille, Douglas A.
§
§
§
§

Mail Stop: AMENDMENT
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT

Sir:

In response to the Office action of December 27, 2004, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Amendments to the Drawings begin on page 15 of this paper and include both an attached replacement sheet and an annotated sheet showing changes.

Remarks/Arguments begin on page 16 of this paper.